



PNP SILICON PLANAR SWITCHING TRANSISTORS

2N2906A 2N2907A TO-18

Switching And Linear Application DC to VHF Amplifier Applications

ABSOLUTE MAXIMUM RATINGS

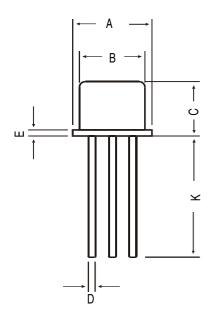
DESCRIPTION	SYMBOL	2N2906A, 07A			UNIT	
Collector -Emitter Voltage	VCEO	60			V	
Collector -Base Voltage	VCEO	60			v	
Emitter -Base Voltage	VEBO	5.0			V	
Collector Current Continuous	IC	600		•		
	PD	400	mA mM			
Power Dissipation @Ta=25 degC	FD				mW	
Derate Above 25deg C		2.28		rnv	V/deg C	
@ Tc=25 degC	PD	1.8		W		
Derate Above 25deg C		10.3		mW/deg C		
Operating And Storage Junction	Tj, Tstg	- 65 to +200			deg C	
Temperature Range						
ELECTRICAL CHARACTERISTICS (T	a=25 deg C l	Unless Otherwise Specified)				
DESCRIPTION	SYMBOL		VAL	LIE		
DESCRIPTION	SYMBOL	TEST CONDITION	VAL MIN			
	SYMBOL VCEO*	TEST CONDITION	VAL MIN 60	_UE MAX -	UNIT	
Collector -Emitter Voltage	VCEO*		MIN	MAX		
Collector -Emitter Voltage Collector -Base Voltage	VCEO* VCBO	IC=10mA,IB=0 IC=10uA.IE=0	MIN 60 60	MAX	V	
Collector -Emitter Voltage Collector -Base Voltage Emitter-Base Voltage	VCEO*	IC=10mA,IB=0	MIN 60	MAX	V V	
Collector -Emitter Voltage Collector -Base Voltage Emitter-Base Voltage	VCEO* VCBO VEBO	IC=10mA,IB=0 IC=10uA.IE=0 IE=10uA, IC=0 VCB=50V, IE=0	MIN 60 60	MAX - - -	V V V	
Collector -Emitter Voltage Collector -Base Voltage Emitter-Base Voltage	VCEO* VCBO VEBO	IC=10mA,IB=0 IC=10uA.IE=0 IE=10uA, IC=0 VCB=50V, IE=0 Ta=150 deg C	MIN 60 60	MAX - - -	V V NA	
Collector -Emitter Voltage Collector -Base Voltage Emitter-Base Voltage	VCEO* VCBO VEBO ICBO	IC=10mA,IB=0 IC=10uA.IE=0 IE=10uA, IC=0 VCB=50V, IE=0 Ta=150 deg C VCB=50V, IE=0	MIN 60 60	MAX - - 10 10	V V NA uA	
Collector -Emitter Voltage Collector -Base Voltage Emitter-Base Voltage Collector-Cut off Current	VCEO* VCBO VEBO ICBO	IC=10mA,IB=0 IC=10uA.IE=0 IE=10uA, IC=0 VCB=50V, IE=0 Ta=150 deg C VCB=50V, IE=0 VCE=30V, VBE=0.5V	MIN 60 60	MAX - - 10 10 50	V V nA uA	
Collector -Emitter Voltage Collector -Base Voltage Emitter-Base Voltage Collector-Cut off Current Base Current	VCEO* VCBO VEBO ICBO ICEX IB	IC=10mA,IB=0 IC=10uA.IE=0 IE=10uA, IC=0 VCB=50V, IE=0 Ta=150 deg C VCB=50V, IE=0 VCE=30V, VBE=0.5V VCE=30V, VBE=0.5V	MIN 60 60	MAX - - 10 10 50 50	V V nA uA nA	
Collector -Emitter Voltage Collector -Base Voltage Emitter-Base Voltage Collector-Cut off Current Base Current	VCEO* VCBO VEBO ICBO	IC=10mA,IB=0 IC=10uA.IE=0 IE=10uA, IC=0 VCB=50V, IE=0 Ta=150 deg C VCB=50V, IE=0 VCE=30V, VBE=0.5V VCE=30V, VBE=0.5V IC=150mA,IB=15mA	MIN 60 60	MAX - - 10 10 50 50 0.4	V V nA uA nA V	
DESCRIPTION Collector -Emitter Voltage Collector -Base Voltage Emitter-Base Voltage Collector-Cut off Current Base Current Collector Emitter Saturation Voltage Base Emitter Saturation Voltage	VCEO* VCBO VEBO ICBO ICBO ICEX IB VCE(Sat)*	IC=10mA,IB=0 IC=10uA.IE=0 IE=10uA, IC=0 VCB=50V, IE=0 Ta=150 deg C VCB=50V, IE=0 VCE=30V, VBE=0.5V VCE=30V, VBE=0.5V	MIN 60 60	MAX - - 10 10 50 50	V V nA uA nA	

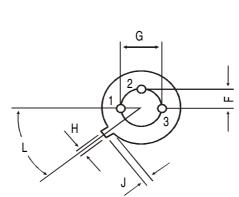
J	()	IC=500mA,IB=50mA	-	2.6	V
			2N2906A	2N2907A	
DC Current Gain	hFE	IC=0.1mA,VCE=10V	>40	>75	
		IC=1mA,VCE=10V	>40	>100	
		IC=10mA,VCE=10V	>40	>100	
		IC=150mA,VCE=10V*	40-120	100-300	
		IC=500mA,VCE=10V*	>40	>50	

DESCRIPTION	SYMBOL	TEST CONDITION	MIN	MAX	UNIT
DYNAMIC CHARACTERISTICS					
Transition Frequency	ft **	ft ** IC=50mA, VCE=20V,f=100MHz		- MHz	
Out-Put Capacitance	Cob	VCB=10V, IE=0,f=100kHz	-	8.0	pF
Input Capacitance	Cib	VBE=2V, IC=0, f=100kHz	-	30	pF
Switching Time					
Delay time	td	IC=150mA,IB1=15mA	-	10	ns
Rise time	tr	VCC=30V	-	40	ns
Turn-On Time	ton			45	ns
Storage time	ts	IC=150mA, IB1=IB2=15mA	-	80	ns
Fall time	tf	VCC=6V	-	30	ns
Turn-Off Time	toff		-	100	ns

**ft is defined as the frequency at which \hfe/ extrapolates to unity

TO-18 Metal Can Package





	DIM	MIN	MAX	
A B	Α	5.24	5.84	
	В	4.52	4.97	
	С	4.31	5.33	
	D	0.40	0.53	
		—	0.76	
Ë.		—	1.27	
in π		—	2.97	
ns		0.91	1.17	
nsic	J	0.71	1.21	
limi	K	12.70		
All	L	45 DEG		



PIN CONFIGURATION 1. EMITTER 2. BASE 3. COLLECTOR

Packing Detail

PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX		
	Details	Net Weight/Qty	Size	Qty	Size	Qty	Gr Wt
T0-18	1K/polybag	350 gm/1K pcs	3" x 7.5" x 7.5"	5.0K	17" x 15" x 13.5"	80.0K	34 kgs

Notes

Disclaimer

The product information and the selection guides facilitate selection of the CDIL's Discrete Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished on the CDIL Web Site/CD is believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Discrete Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

CDIL strives for continuous improvement and reserves the right to change the specifications of its products without prior notice.



CDIL is a registered Trademark of **Continental Device India Limited** C-120 Naraina Industrial Area, New Delhi 110 028, India. Telephone + 91-11-2579 6150, 4141 1112 Fax + 91-11-2579 5290, 4141 1119 email@cdil.com www.cdilsemi.com

Data Sheet